

TOSHIBA Field Effect Transistor    Silicon P/N Channel MOS Type

SSM6L12TU

High-Speed Switching Applications

- Optimum for high-density mounting in small packages
- Low ON-resistance    Q1:  $R_{DS(ON)} = 180m\Omega$  (max) (@ $V_{GS} = 2.5\text{ V}$ )  
                                  Q2:  $R_{DS(ON)} = 430m\Omega$  (max) (@ $V_{GS} = -2.5\text{ V}$ )

Q1 Absolute Maximum Ratings ( $T_a = 25^{\circ}\text{C}$ )

Characteristics		Symbol	Rating	Unit
Drain-source voltage		$V_{DS}$	30	V
Gate-source voltage		$V_{GSS}$	$\pm 12$	V
Drain current	DC	$I_D$	0.5	A
	Pulse	$I_{DP}$	1.5	

Q2 Absolute Maximum Ratings ( $T_a = 25^{\circ}\text{C}$ )

Characteristics		Symbol	Rating	Unit
Drain-source voltage		$V_{DS}$	-20	V
Gate-source voltage		$V_{GSS}$	$\pm 12$	V
Drain current	DC	$I_D$	-0.5	A
	Pulse	$I_{DP}$	-1.5	

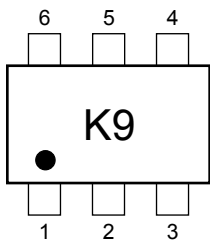
Absolute Maximum Ratings (Q1,Q2 Common)  
( $T_a = 25^{\circ}\text{C}$ )

Characteristics	Symbol	Rating	Unit
Power dissipation	$P_D$ (Note 1)	500	mW
Channel temperature	$T_{ch}$	150	$^{\circ}\text{C}$
Storage temperature range	$T_{stg}$	-55 to 150	$^{\circ}\text{C}$

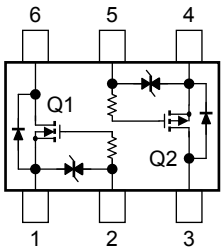
Note:    Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.  
          Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1:    Mounted on FR4 board. (total dissipation)  
          (25.4 mm  $\times$  25.4 mm  $\times$  1.6 mm, Cu Pad: 645 mm<sup>2</sup>)

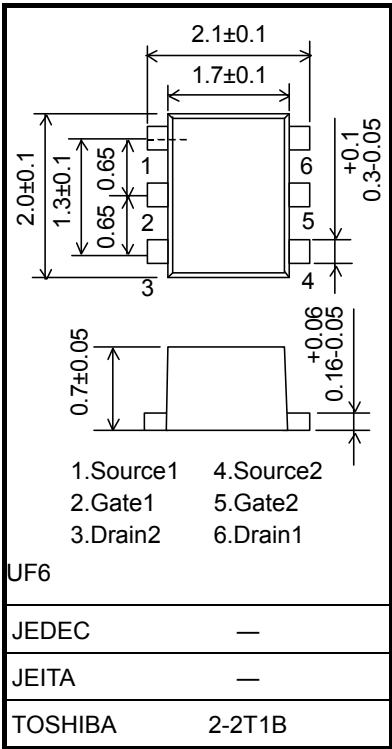
Marking



Equivalent Circuit (top view)



Unit: mm



Weight: 7.0 mg (typ.)

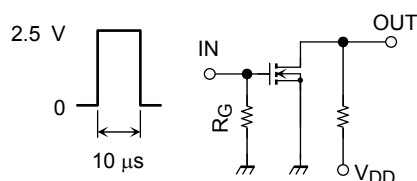
## Q1 Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0$	—	—	$\pm 1$	$\mu\text{A}$
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 1 \text{ mA}, V_{GS} = 0$	30	—	—	V
	$V_{(BR)DSX}$	$I_D = 1 \text{ mA}, V_{GS} = -12 \text{ V}$	18	—	—	
Drain cut-off current	$I_{DSS}$	$V_{DS} = 30 \text{ V}, V_{GS} = 0$	—	—	1	$\mu\text{A}$
Gate threshold voltage	$V_{th}$	$V_{DS} = 3 \text{ V}, I_D = 0.1 \text{ mA}$	0.5	—	1.1	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3 \text{ V}, I_D = 0.25 \text{ A}$ (Note 2)	1.0	2.0	—	S
Drain-source on-resistance	$R_{DS(ON)}$	$I_D = 0.50 \text{ A}, V_{GS} = 4.5 \text{ V}$ (Note 2)	—	120	145	$\text{m}\Omega$
		$I_D = 0.25 \text{ A}, V_{GS} = 2.5 \text{ V}$ (Note 2)	—	140	180	
Input capacitance	$C_{iss}$	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	—	245	—	pF
Reverse transfer capacitance	$C_{rss}$	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	—	33	—	pF
Output capacitance	$C_{oss}$	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	—	41	—	pF
Switching time	Turn-on time	$V_{DD} = 10 \text{ V}, I_D = 0.25 \text{ A},$ $V_{GS} = 0 \text{ to } 2.5 \text{ V}, R_G = 4.7 \Omega$	—	9	—	ns
	Turn-off time		—	15	—	

Note 2: Pulse test

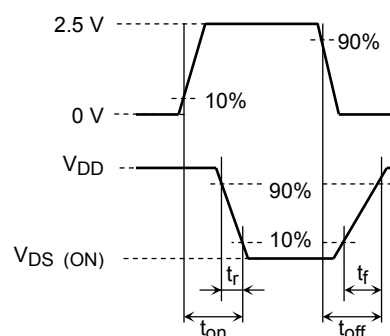
## Switching Time Test Circuit

(a) Test Circuit



$V_{DD} = 10 \text{ V}$   
 $R_G = 4.7 \Omega$   
 Duty  $\leq 1\%$   
 $V_{IN}$ :  $t_r, t_f < 5 \text{ ns}$   
 Common Source  
 $T_a = 25^\circ\text{C}$

(b)  $V_{IN}$



(c)  $V_{OUT}$

## Precaution

$V_{th}$  can be expressed as the voltage between gate and source when the low operating current value is  $I_D = 100 \mu\text{A}$  for this product. For normal switching operation,  $V_{GS(ON)}$  requires a higher voltage than  $V_{th}$  and  $V_{GS(OFF)}$  requires a lower voltage than  $V_{th}$ .

(The relationship can be established as follows:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ )

Please take this into consideration when using the device.

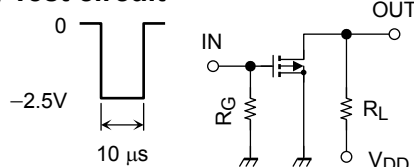
## Q2 Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 12V, V_{DS} = 0$	—	—	$\pm 1$	$\mu A$
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = -1 mA, V_{GS} = 0$	-20	—	—	V
	$V_{(BR)DSX}$	$I_D = -1 mA, V_{GS} = +12 V$	-8	—	—	
Drain cut-off current	$I_{DSS}$	$V_{DS} = -20 V, V_{GS} = 0$	—	—	-1	$\mu A$
Gate threshold voltage	$V_{th}$	$V_{DS} = -3 V, I_D = -0.1 mA$	-0.5	—	-1.1	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = -3 V, I_D = -0.25 A$ (Note 3)	0.65	1.3	—	S
Drain-source on-resistance	$R_{DS(ON)}$	$I_D = -0.25 A, V_{GS} = -4 V$ (Note 3)	—	210	260	$m\Omega$
		$I_D = -0.25 A, V_{GS} = -2.5 V$ (Note 3)	—	310	430	
Input capacitance	$C_{iss}$	$V_{DS} = -10 V, V_{GS} = 0, f = 1 MHz$	—	218	—	pF
Reverse transfer capacitance	$C_{rss}$	$V_{DS} = -10 V, V_{GS} = 0, f = 1 MHz$	—	42	—	pF
Output capacitance	$C_{oss}$	$V_{DS} = -10 V, V_{GS} = 0, f = 1 MHz$	—	52	—	pF
Switching time	Turn-on time	$V_{DD} = -10 V, I_D = -0.25 A,$ $V_{GS} = 0 \text{ to } -2.5 V, R_G = 4.7 \Omega$	—	16	—	ns
	Turn-off time		—	15	—	

Note3: Pulse test

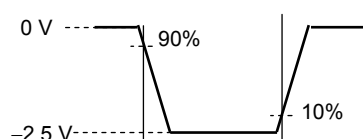
## Switching Time Test Circuit

### (a) Test circuit

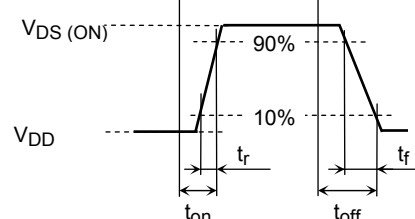


$V_{DD} = -10 V$   
 $R_G = 4.7 \Omega$   
 Duty  $\leq 1\%$   
 $V_{IN}$ :  $t_r, t_f < 5 ns$   
 Common Source  
 $T_a = 25^\circ C$

### (b) $V_{IN}$



### (c) $V_{OUT}$



## Precaution

$V_{th}$  can be expressed as the voltage between gate and source when the low operating current value is  $I_D = -100 \mu A$  for this product. For normal switching operation,  $V_{GS(ON)}$  requires a higher voltage than  $V_{th}$  and  $V_{GS(OFF)}$  requires a lower voltage than  $V_{th}$ .

(The relationship can be established as follows:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ )

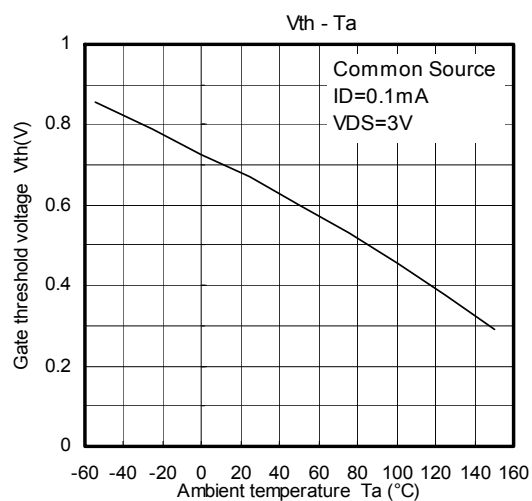
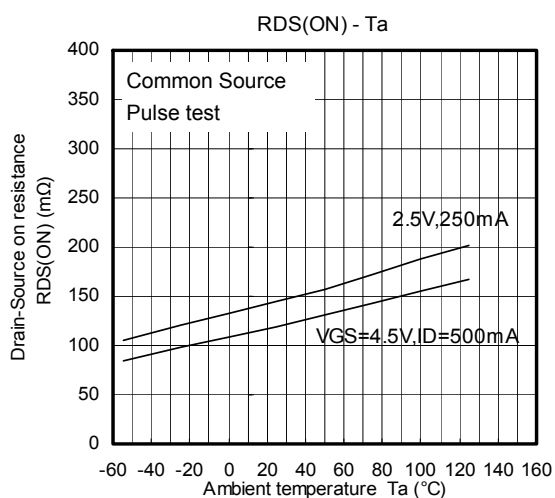
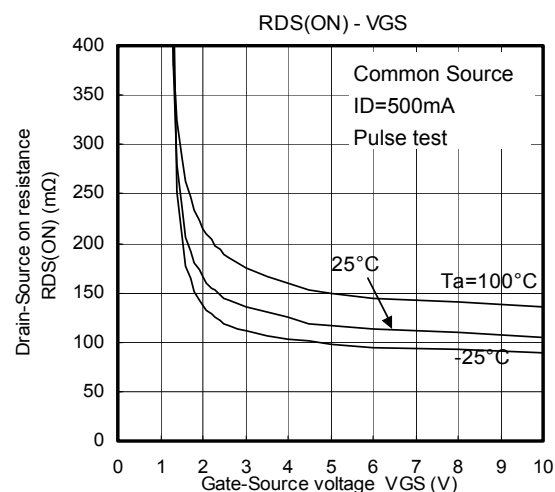
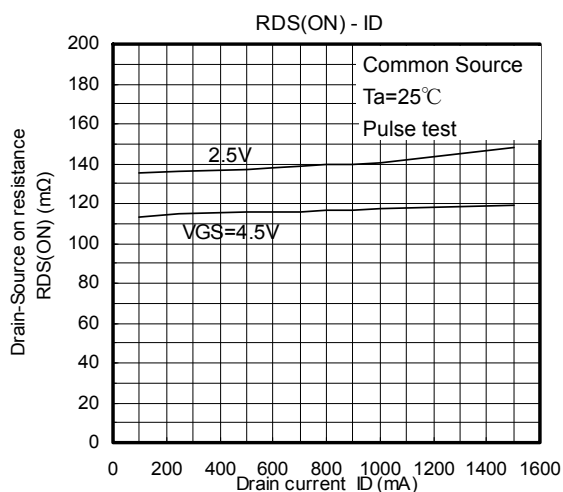
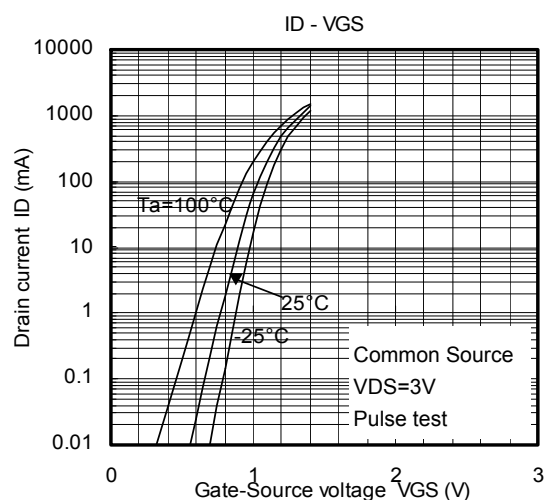
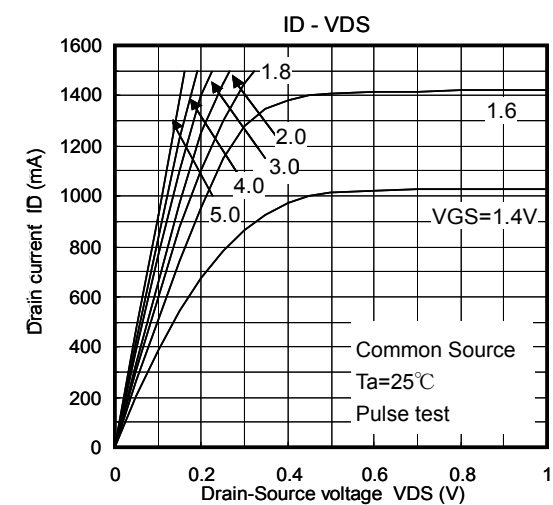
Please take this into consideration when using the device.

## Handling Precaution

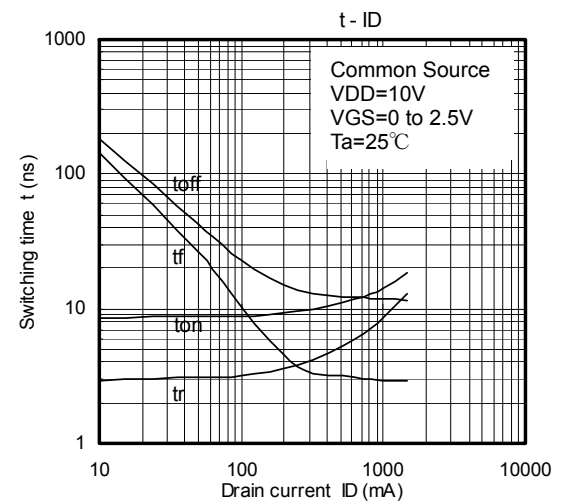
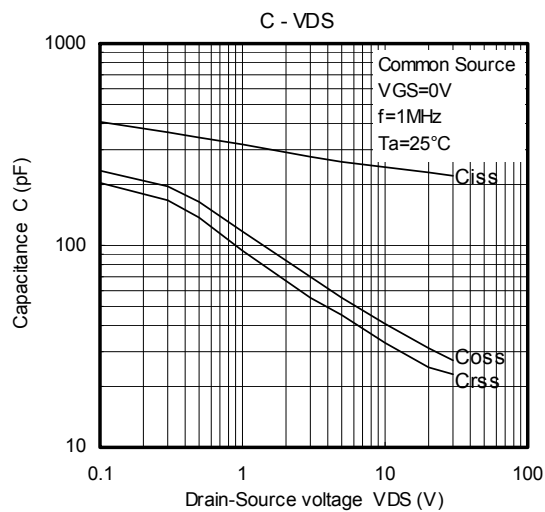
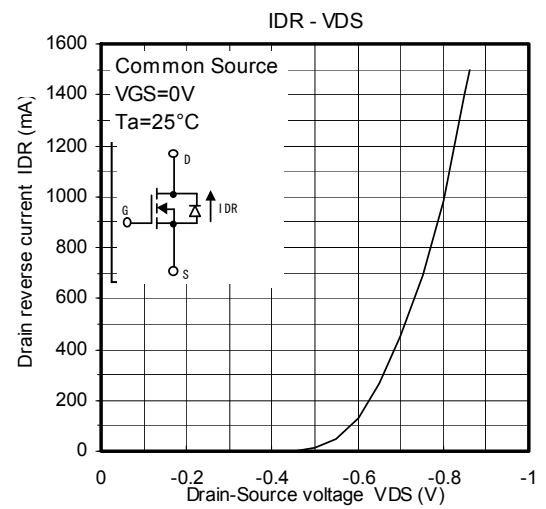
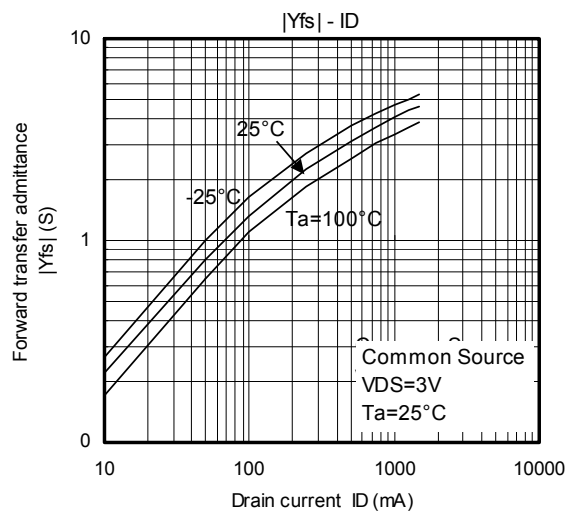
When handling individual devices (which are not yet mounted on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Thermal resistance  $R_{th(ch-a)}$  and power dissipation  $P_D$  vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration

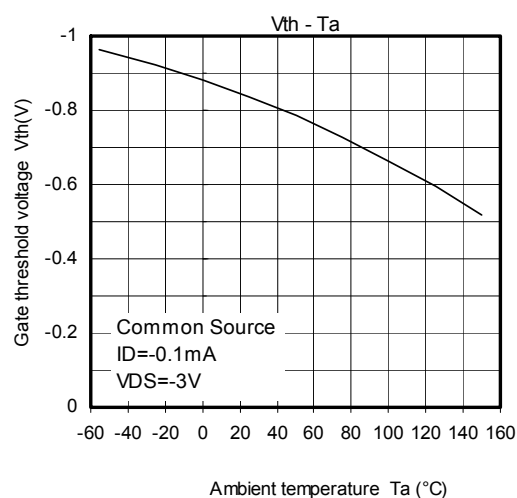
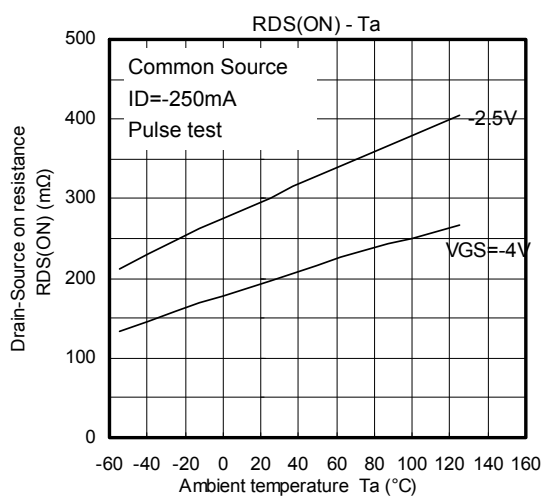
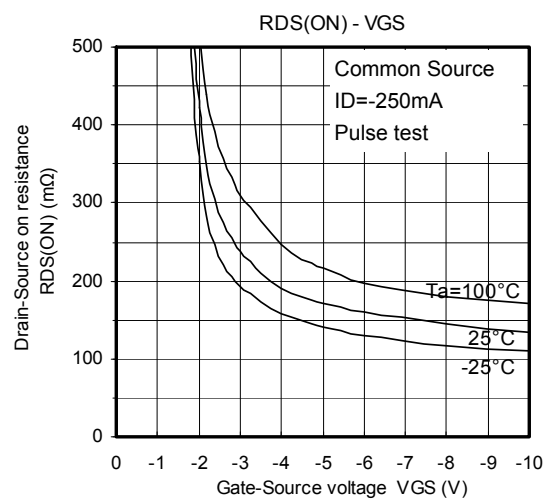
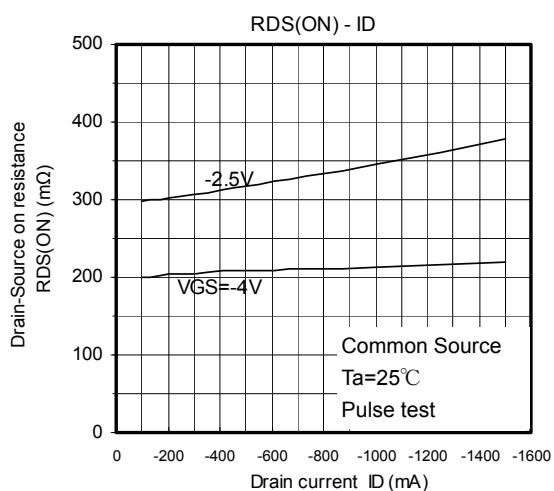
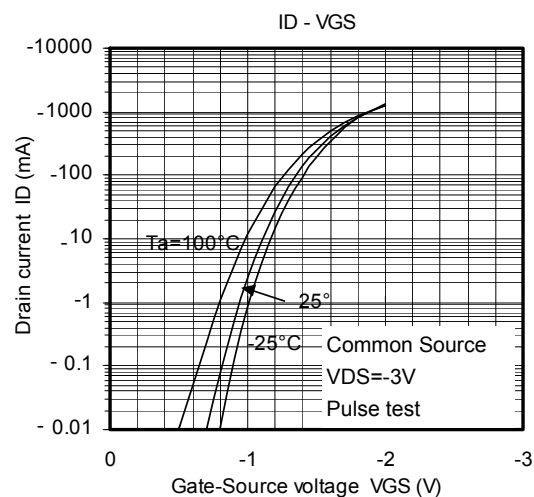
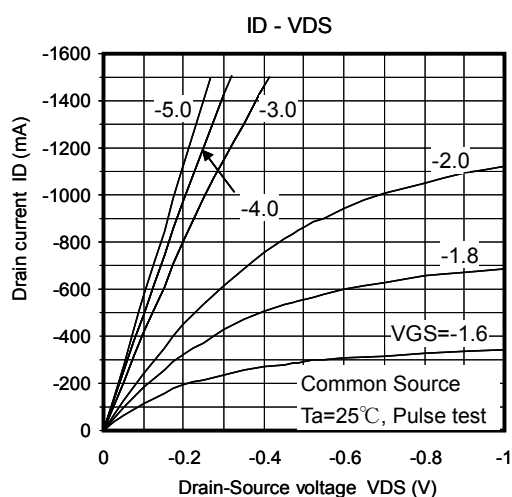
## Q1(Nch MOS FET)



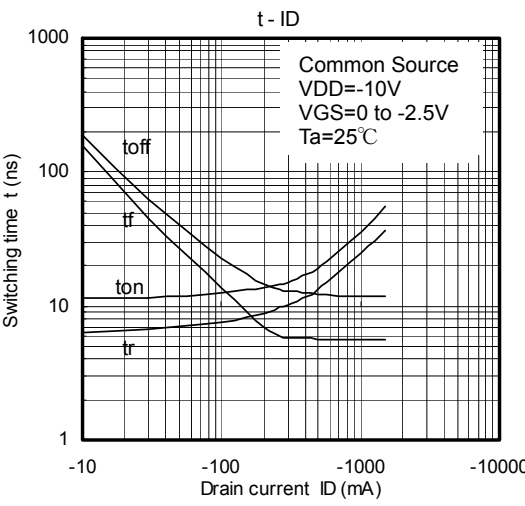
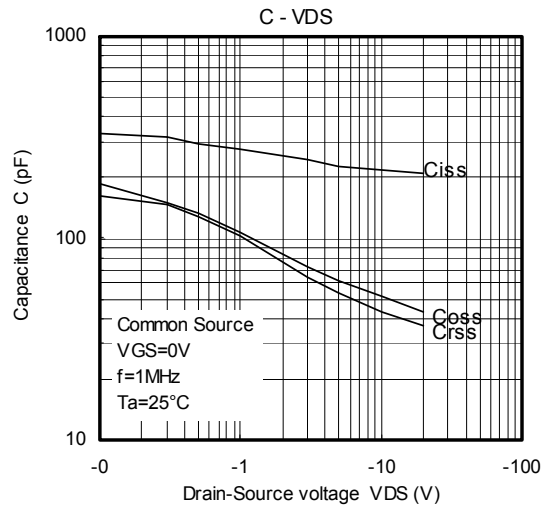
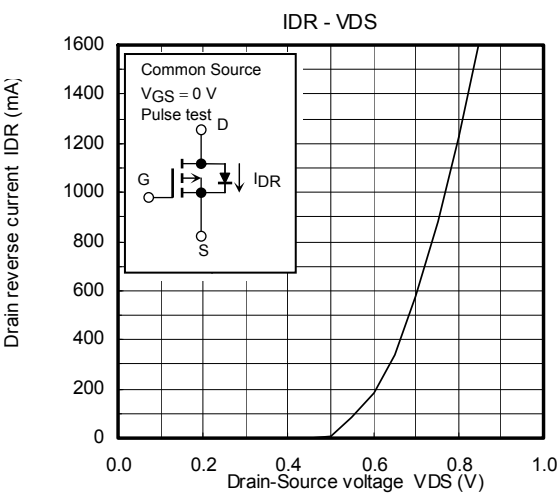
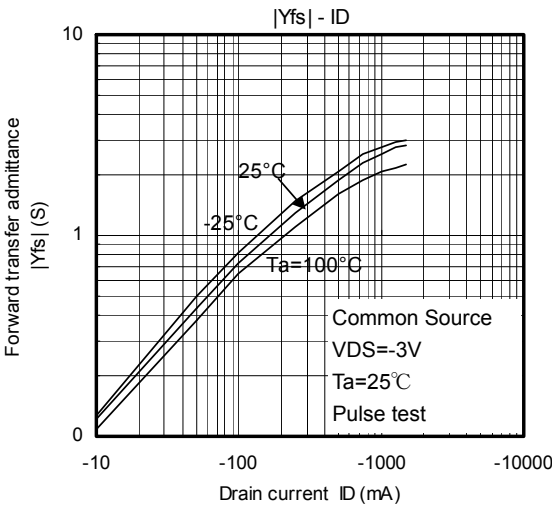
## Q1(Nch MOS FET)

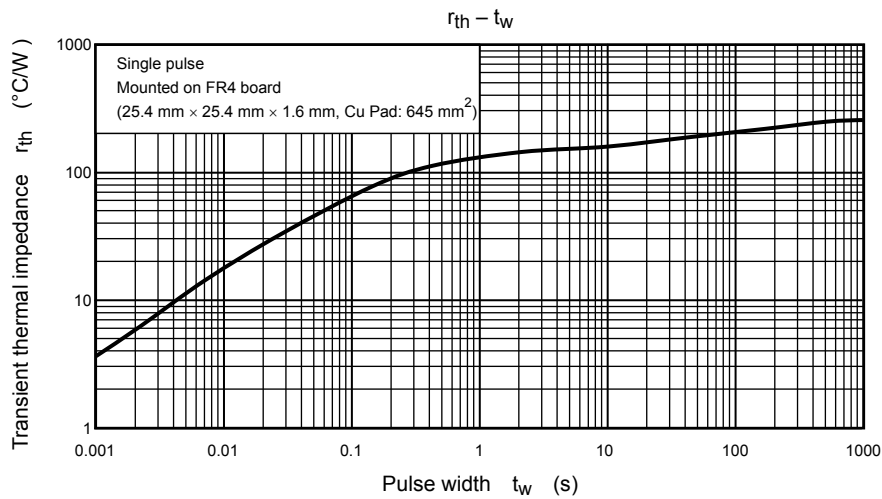
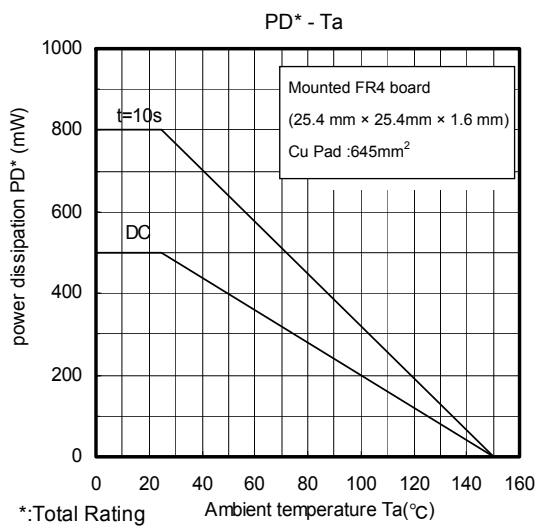


## Q2(Pch MOS FET)



Q2(Pch MOS FET)







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